

FL IF MEM 2TX-D - Memory modul



2832483

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Memory module, 2 port twisted pair module for saving the switch configuration



Commercial data

Item number	2832483
Packing unit	1 pc
Note	Made to order (non-returnable)
Sales key	NULL
Product key	DNN123
GTIN	4017918974497
Weight per piece (including packing)	91.8 g
Weight per piece (excluding packing)	91.8 g
Customs tariff number	85176200
Country of origin	DE

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Technical data

Product properties

Product type	Storage medium
Type	fine granularity

System properties

Functionality

Basic functions	Configuration memory (plug-in)
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Electrical properties

Supply

Supply voltage	via head station
Power supply connection	from FL SWITCH MM HS or MXT
Typical current consumption	10 mA

Interfaces

Ethernet 10/100Base T

Connection method	RJ45 jack
Transmission speed	10/100 Mbps
Transmission physics	Copper
Transmission length	100 m
No. of channels	2

Dimensions

Width	31 mm
Height	78 mm
Depth	72.5 mm

Material specifications

Color	green
Housing material	PA

Environmental and real-life conditions

Ambient conditions

Degree of protection	IP20
Ambient temperature (operation)	0 °C ... 55 °C (non-condensing)
Ambient temperature (storage/transport)	-20 °C ... 70 °C
Permissible humidity (operation)	10 % ... 95 % (non-condensing)
Permissible humidity (storage/transport)	10 % ... 95 % (non-condensing)

EMC data

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Electromagnetic compatibility	Conformance with EMC Directive 2004/108/EC
Conformance with EMC directives	IEC 61000-6-2 IEC 61000-4-2 (ESD) Criterion B
	IEC 61000-4-3 (immunity to radiated interference) Criterion A
	IEC 61000-4-4 (burst) Criterion A
	IEC 61000-4-5 (surge) Criterion A
	IEC 61000-4-6 (immunity to conducted interference) Criterion A
	IEC 61000-4-8 (immunity to magnetic fields) Criterion A
	EN 55022 (emitted interference) Criterion A
Noise immunity	EN 61000-6-2:2005
Noise emission	
Standards/regulations	EN 61000-6-3/-4

Mounting

Mounting type	In the host system
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Environmental product compliance

China RoHS

Environment friendly use period (EFUP)	EFUP-25 An article-related China RoHS declaration table can be found in the download area for the respective article under "Manufacturer declaration". For all articles with EFUP-E, no China RoHS declaration table issued and required.
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EU REACH SVHC

REACH candidate substance (CAS No.)	No substance above 0.1 wt%
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